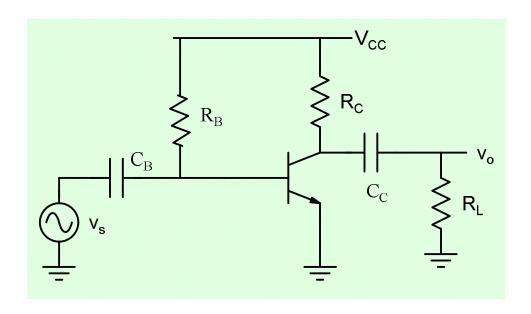
## **EE210: Microelectronics-I**

# Lecture-16 :BJT Amplifier-part-5 Biasing

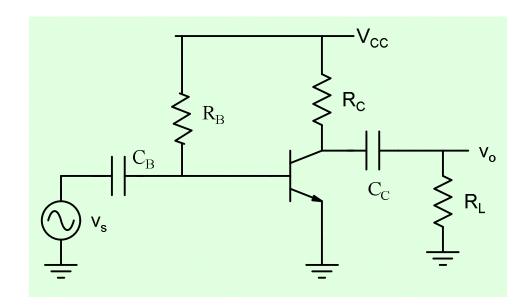
Instructor - Y. S. Chauhan

Slides from: B. Mazhari Dept. of EE, IIT Kanpur



$$\begin{aligned} \text{Bias Point : } & I_{CQ}, V_{CEQ} \\ R_{in} \sim r_{\pi} &= \frac{V_{T}}{I_{CQ}} \beta \\ v_{om} &= Min \left\{ V_{CEQ} - V_{CEsat}; \left( I_{CQ} \times R_{C} \left\| R_{L} \right) \times \left( \frac{HD_{2}}{25} \right) \right\} \end{aligned}$$

# Bias Stability



$$I_{CQ} = \left(\frac{V_{CC} - V_{BE}}{R_B}\right) \times \beta$$

$$S_{V_{CC}} = \frac{\Delta I_{CQ}/I_{CQ}}{\Delta V_{CC}/V_{CC}} = \frac{V_{CC}}{V_{CC} - 0.7}$$
  $S_{V_{BE}} = \frac{V_{BE}}{V_{CC} - 0.7}$   $S_{\beta} = 1$ 

Bias Point :  $I_{CO}, V_{CEO}$ 

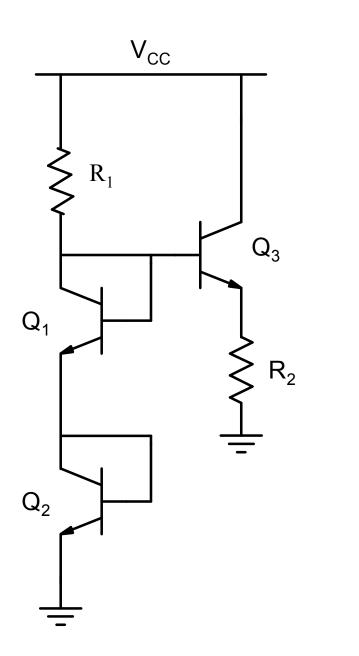
Sources of variation:

- 1. Supply voltage
- 2. Temperature
  - 3. Current gain β

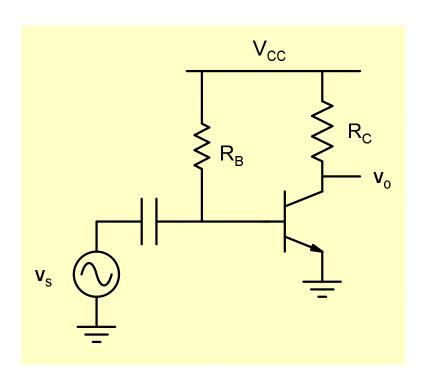
$$S_{x} = \frac{\Delta I_{CQ} / I_{CQ}}{\Delta x / x}$$

$$S_{V_{BE}} = \frac{V_{BE}}{V_{CC} - 0.7}$$
  $S_{\beta} = 1$ 

# Supply Independent Current (?)



$$I_{R2} \sim \frac{0.7}{R_2}$$

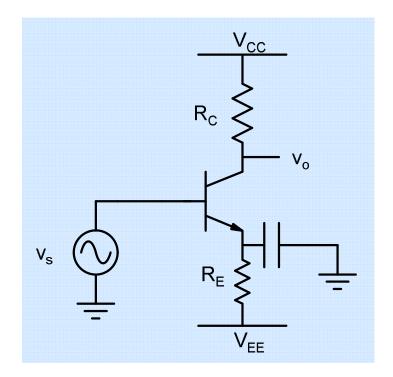


$$I_{CQ} = \beta \times I_{BQ}$$

$$I_{CQ} = \beta \times I_{BQ}$$

$$I_{BQ} = \frac{V_{CC} - 0.7}{R_B}$$

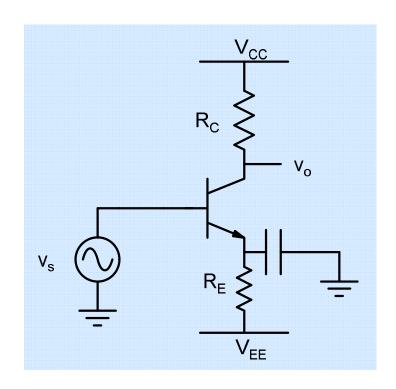
$$S_{\beta} = \frac{\Delta I_{CQ} / I_{CQ}}{\Delta \beta / \beta} = 1$$

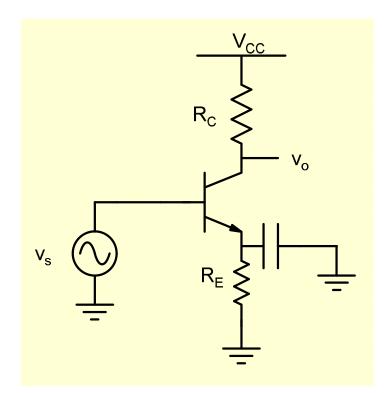


$$I_{CQ} = \left(\frac{\beta}{\beta + 1}\right) I_{EQ}$$

$$I_{EQ} = \frac{-0.7 - V_{EE}}{R_E}$$

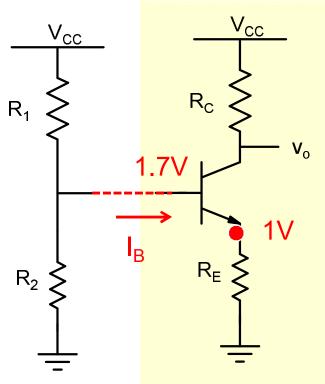
$$S_{\beta} << 1$$





$$I_{EQ} = \frac{V_E}{R_E}$$

$$I_{CQ} = \left(\frac{\beta}{\beta + 1}\right) I_{EQ}$$



$$R_{1} = \frac{V_{CC}}{R_{1}}$$

$$R_{2} = \frac{V_{E}}{R_{E}}$$

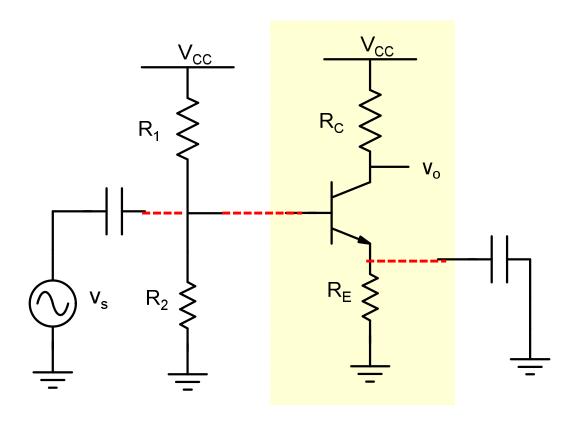
$$V_{CC} = I_{CQ}R_{C} + V_{CEQ} + V_{EQ}$$

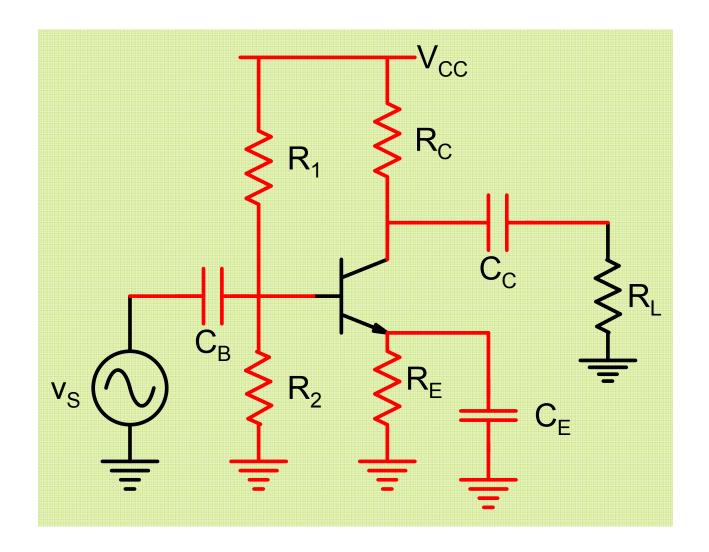
$$|A_{VO}| = \frac{I_{CQ}R_{C}}{V_{T}}$$

$$V_{Om} = Min\left\{V_{CEQ} - V_{CESat}; \left(I_{CQ} \times R_{C} \| R_{L}\right) \times \left(\frac{HD_{2}}{25}\right)\right\}$$

$$V_{CC}\left(\frac{R_2}{R_1 + R_2}\right) = 1.7$$

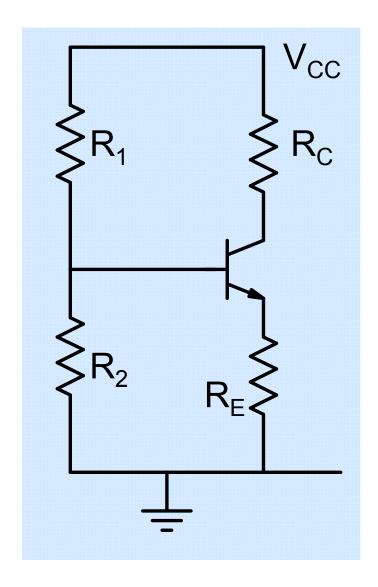
$$\frac{V_{CC}}{R_1 + R_2} >> I_B$$

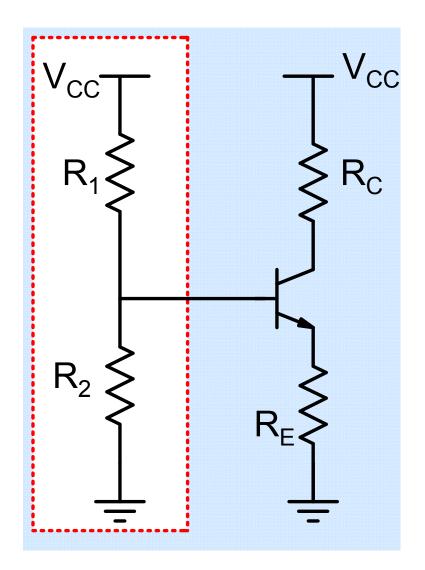




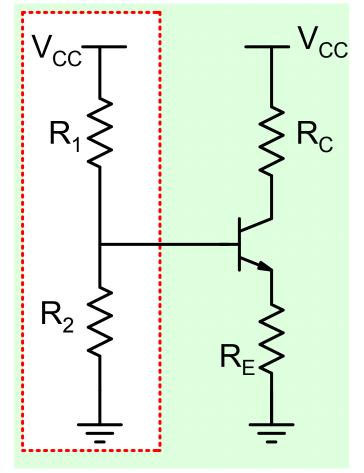
A good biasing circuit for discrete implementation

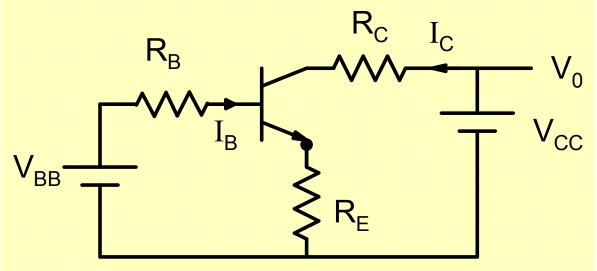
## **Bias Point dc Analysis**





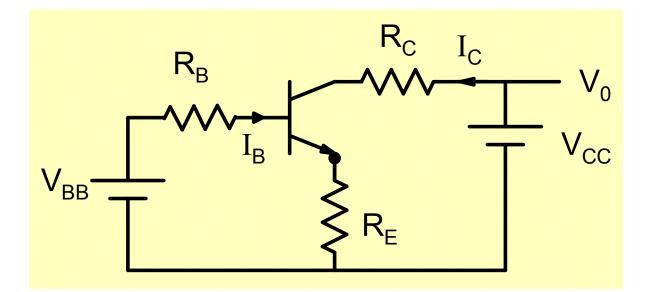
### dc Analysis





$$V_{TH} = V_{BB} = rac{V_{CC}R_2}{R_1 + R_2}$$
  $R_{TH} = R_B = R_1 \parallel R_2$ 

#### dc Analysis



$$V_{CC}$$
  $V_{BB} = \frac{V_{CC}R_2}{R_1 + R_2}$   $R_B = R_1 \parallel R_2$ 

$$V_{BB} \cong I_B R_B + V_{BE} + I_C R_E$$

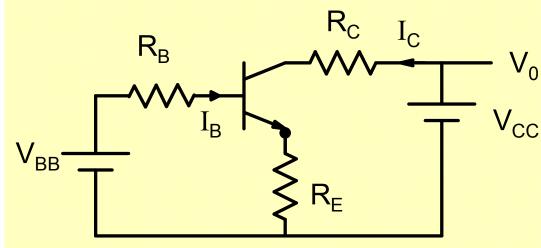
$$I_C = \frac{V_{BB} - V_{BE}}{\frac{R_B}{\beta} + R_E}$$

$$S = \frac{\Delta I_C / I_C}{\Delta \beta / \beta} = \frac{1}{1 + \frac{R_E \beta}{R_B}}$$

$$R_E >> \frac{R_B}{\beta}$$

$$R_E >> \frac{R_B}{\beta}$$

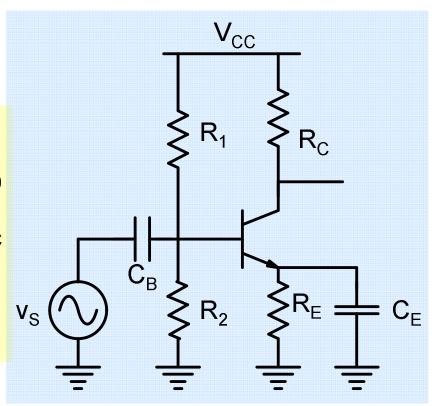
$$I_{QQ}R_E >> I_{QQ}\frac{R_B}{\beta} = I_BR_B$$



$$V_{BB} = I_B R_B + V_{BE} + I_C R_E$$

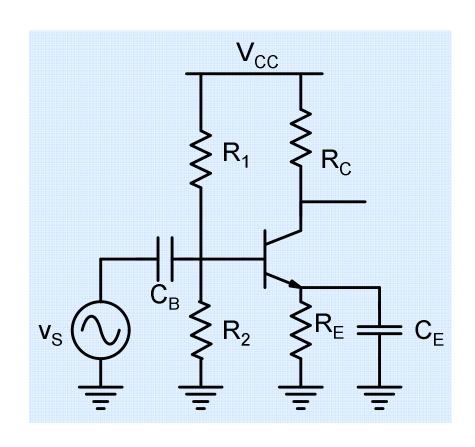
$$\cong V_{BE} + I_C R_E$$

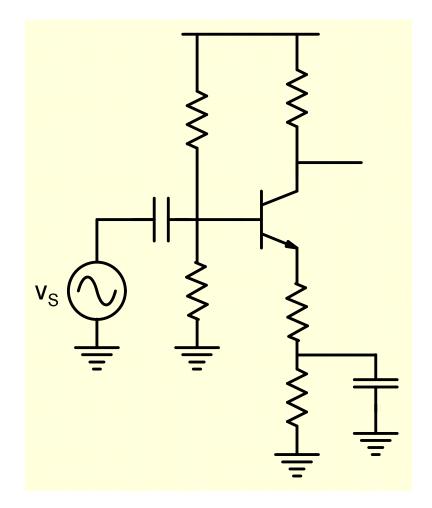
$$V_{BB} \cong \frac{V_{CC}R_2}{R_1 + R_2}$$



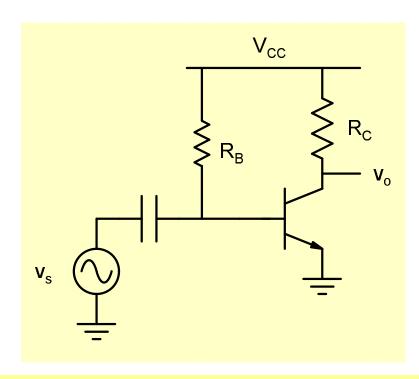
$$V_{CC} = I_{CQ}R_C + V_{CEQ} + V_{EQ}$$

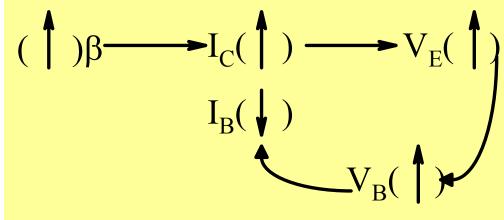
Stability comes at a price of reduced gain, swing etc



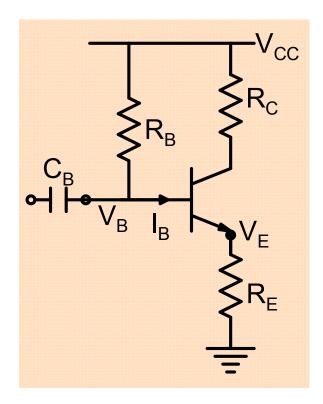


Bypassed emitter resistance for stability and un-bypassed for improving linearity, input resistance etc





$$V_{CC} = I_{CQ}R_C + V_{CEQ} + V_{EQ}$$

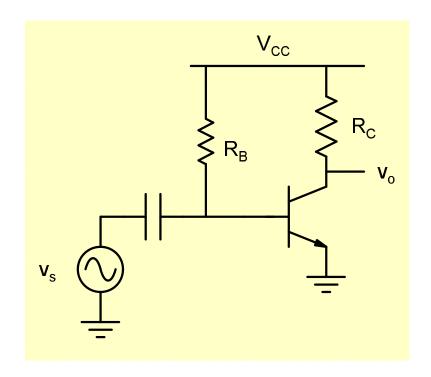


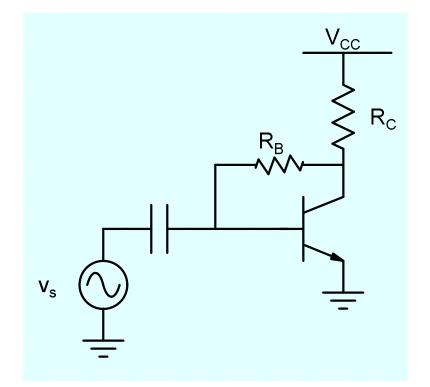
$$S = \frac{\Delta I_C / I_C}{\Delta \beta / \beta} = \frac{1}{1 + \frac{R_E}{R_B / \beta}}$$

$$R_{E} \gg \frac{R_{B}}{\beta}$$
  $I_{QQ}R_{E} \gg I_{QQ}\frac{R_{B}}{\beta} = I_{B}R_{B}$ 

$$\begin{split} V_{CC} &= I_{BQ} R_B + V_{BEQ} + V_E \\ &\cong V_{BEQ} + V_E \end{split}$$

G-Number





$$I_C = \left(\frac{V_{CC} - 0.7}{R_C}\right) \times \left(\frac{\beta}{1 + \beta + R_B/R_C}\right)$$

$$V_{CEQ} = V_{CC} \left( \frac{1 + R_B / R_C}{1 + \beta + R_B / R_C} \right) + 0.7 \left( \frac{\beta}{1 + \beta + R_B / R_C} \right)$$

$$R_{in} = r_{\pi} \left\| \frac{R_B}{1 - A_V} \right\|$$

$$( \uparrow )\beta \longrightarrow I_{C}( \uparrow ) \longrightarrow V_{C}( \downarrow )$$

$$I_{C}( \downarrow ) \longrightarrow I_{B}( \downarrow )$$